

## QUARTZ CRYSTAL OSCILLATOR

**■ GENERAL DESCRIPTION**

The NJU6362A is a C-MOS quartz crystal oscillator which consists of an oscillation amplifier and 3-state output buffer.

The oscillation frequency is as wide as up to 50MHz and the symmetry of 45-55% is realized over full oscillation frequency range.

The oscillation amplifier incorporates feed-back resistance and oscillation capacitors ( $C_g$ ,  $C_d$ ), therefore, it requires no external component except quartz crystal.

**■ FEATURES**

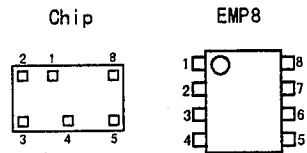
- Operating Voltage — 3.0~6.0V
- Maximum Oscillation Frequency — 50MHz
- Low Operating Current
- High Fan-out — LSTTL 10
- 3-state Output Buffer
- Oscillation Capacitors  $C_g$  and  $C_d$  on-chip
- Oscillation Output Stand-by Function
- Package Outline — Chip/EMP8
- C-MOS Technology

**■ PACKAGE OUTLINE**


NJU6362AC



NJU6362AE

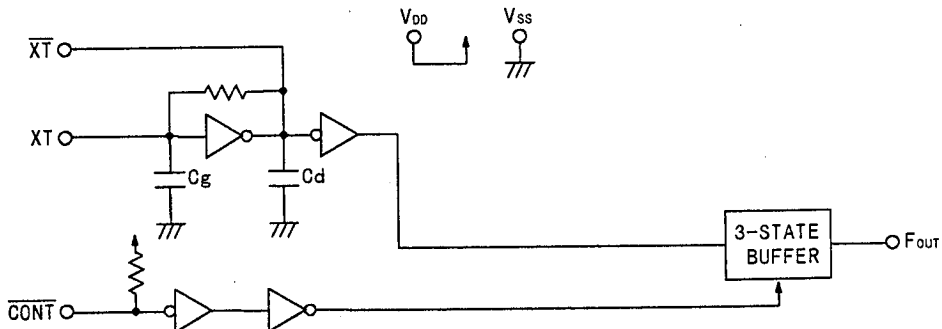
**■ PAD LOCATION/PIN CONFIGURATION**

**■ COORDINATES**

No.	PAD	X	Y
1	CONT	515	648
2	XT	231	648
3	$\overline{XT}$	231	168
4	$V_{SS}$	734	152
5	$F_{OUT}$	1091	172
6	NC	—	—
7	NC	—	—
8	$V_{DD}$	1091	628

Chip Size : 1.29x0.8mm

Chip Thickness :  $400 \pm 30 \mu\text{m}$

Note) There are no PAD of No. 6 and 7 on the chip.

**■ BLOCK DIAGRAM**


**■ TERMINAL DESCRIPTION**

No.	SYMBOL	F U N C T I O N	
1	$\overline{\text{CONT}}$	3-State Output Control	
		$\overline{\text{CONT}}$	$F_{\text{OUT}}$
		H or Open	Output frequency $f_o$
	L	Output High Impedance	
2	$\overline{\text{XT}}$	Quartz Crystal Connecting terminals	
3	$\overline{\text{XT}}$		
4	$V_{SS}$	GND	
5	$F_{\text{OUT}}$	Output frequency $f_o$	
8	$V_{DD}$	+ 5V	

**■ ABSOLUTE MAXIMUM RATINGS**

(Ta=25°C)

P A R A M E T E R	SYMBOL	R A T I N G S	UNIT
Supply Voltage	$V_{DD}$	-0.5 ~ +7.0	V
Input Voltage	$V_{IN}$	$V_{SS}-0.5 \sim V_{DD}+0.5$	V
Output Voltage	$V_o$	-0.5 ~ $V_{DD}+0.5$	V
Input Current	$I_{IN}$	±10	mA
Output Current	$I_o$	±25	mA
Power Dissipation (EMP)	$P_o$	200	mW
Operating Temperature Range	$T_{opr}$	-40 ~ + 85	°C
Storage Temperature Range	$T_{stg}$	-65 ~ +150	°C

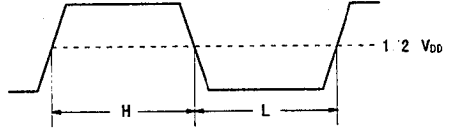
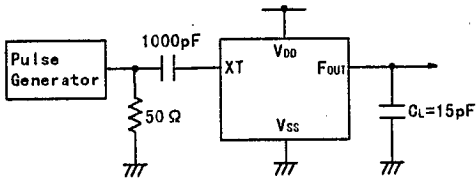
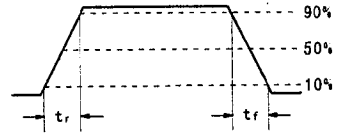
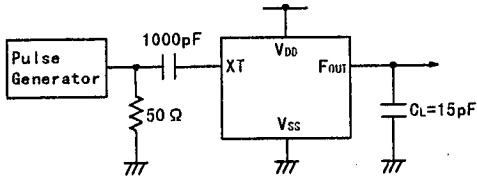
**■ ELECTRICAL CHARACTERISTICS**

 ( Ta=25°C,  $V_{DD}=5V$  )

P A R A M E T E R	SYMBOL	C O N D I T I O N S	MIN	TYP	MAX	UNIT
Operating Voltage	$V_{DD}$		3		6	V
Operating Current	$I_{DD}$	$f_{osc}=16\text{MHz}$ , No load			10	mA
Stand-by Current	$I_{st}$	$\overline{\text{CONT}}=\overline{\text{XT}}=V_{SS}$ , No load (Note)			1	μA
Input Voltage	$V_{IH}$		3.5		5.0	V
	$V_{IL}$		0		1.5	
Output Current	$I_{OH}$	$V_{OH}=4.5V$	5.5			mA
	$I_{OL}$	$V_{OL}=0.5V$	5.5			
Input Current	$I_{IN}$	$\overline{\text{CONT}}=V_{SS}$	125	250	500	μA
3-st. Off-leakage Current	$I_{oz}$	$\overline{\text{CONT}}=V_{SS}$ , $F_{\text{OUT}}=V_{DD}$ or $V_{SS}$			±0.1	μA
Internal Capacitor	$C_g/C_d$			28		pF
Max. Oscillation Freq.	$f_{MAX}$		50			MHz
Output Signal Symmetry	SYM	$C_L=15\text{pF}$ at $1/2V_{DD}$	45	50	55	%
Output Signal Rise Time	$t_r$	$C_L=15\text{pF}$ , 10%-90%			8	ns
Output Signal Fall Time	$t_f$	$C_L=15\text{pF}$ , 90%-10%			8	ns

 Note) Excluding input current on  $\overline{\text{CONT}}$  terminal.

**MEASUREMENT CIRCUITS**

 (1) Output Signal Symmetry ( $C_L=15\text{pF}$ )

 (2) Output Signal Rise / Fall Time ( $C_L=15\text{pF}$ )


## MEMO

**[CAUTION]**

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